NSN 5961-01-414-8645

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-414-8645 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** 0.034 inches **Overall Width:** Between 0.083 inches and 0.098 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 50.0 reverse voltage, instantaneous all semiconductor device diode **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Capacitance Rating In Picofarads:** 0.35 all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: